

PNP Darlington Transistor

This device is designed for applications requiring extremely high current gain at currents to 800 mA. Sourced from Process 61. See MPSA64 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	30	V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	Collector Current - Continuous	1.2	A
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units	
		MPSA63	*MMBTA63	**PZTA63	-
PD	Total Device Dissipation	625	350	1,000	mW
	Derate above 25°C	5.0	2.8	8.0	mW/°C
R _{0JC}	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

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PNP Darlington Transistor (continued)

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Electrical Characteristics TA = 25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, \ I_{\rm B} = 0$	30		V
-					
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, I_E = 0$		100	nA

ON CHARACTERISTICS*

h _{FE}	DC Current Gain	I_{C} = 10 mA, V_{CE} = 5.0 V I_{C} = 100 mA, V_{CE} = 5.0 V	5,000 10,000		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C}$ = 100 mA, $I_{\rm B}$ = 0.1 mA		1.5	V
V _{BE(on)}	Base-Emitter On Voltage	I_{C} = 100 mA, V_{CE} = 5.0 V		2.0	V

SMALL SIGNAL CHARACTERISTICS

f _T Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 100 MHz	125	MHz
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*Pulse Test: Pulse Width $\leq 300 \ \mu s, \ \text{Duty Cycle} \leq 2.0\%$

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Product Status	Definition
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